NSN 5961-00-253-2573

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-253-2573 **Inclosure Material:** Metal **Overall Length:** Between 0.165 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 625.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig:

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